



Declaration of conformity

For the following equipment :

Product Name: Switching Power Supplies

Model Designation: HSP-200-x(x=4.2, 5)

is herewith confirmed to comply with the requirements set out in the Council Directive, the following standards were applied :

RoHS Directive (2011/65/EU)

Low Voltage Directive (2014/35/EU) :

EN60950-1:2006+A11+A1+A12+A2

TUV certificate No : R50302319

Electromagnetic Compatibility Directive (2014/30/EU) :

EMI (Electro-Magnetic Interference)

Conducted emission	EN55032:2015	Class B
Radiated emission	EN55032:2015	Class B
Harmonic current	EN61000-3-2: 2014	
Voltage flicker	EN61000-3-3: 2013	

EMS (Electro-Magnetic Susceptibility)

EN55024:2010+A1:2015

ESD air	EN61000-4-2:2009	Level 3	8KV
ESD contact	EN61000-4-2:2009	Level 2	4KV
RF field susceptibility	EN61000-4-3:2006+A1:2008+A2:2010	Level 2	3V/m
EFT bursts	EN61000-4-4:2012	Level 2	1KV/5KHz
Surge susceptibility	EN61000-4-5:2014	Level 4	2KV/Line-Line
Surge susceptibility	EN61000-4-5:2014	Level 4	4KV/Line-Earth
Conducted susceptibility	EN61000-4-6:2014	Level 2	3V
Magnetic field immunity	EN61000-4-8:2010	Level 2	3A/m
Voltage dip, interruption	EN61000-4-11:2004 >95% dip 0.5 periods 30% dip 25 periods >95% interruptions 250 periods		

Note:

Component power supply will be operated with a final equipment. Since EMC performance will be affected by the complete installation, the final equipment manufacturers must re-qualify EMC Directive on the complete installation again.

Tests above are only to be performed with resistive loads.

For guidance on how to perform these EMC tests, please refer to TDF (Technical Documentation File).

This Declaration is effective from serial number HB7xxxxxx

Person responsible for marking this declaration :

MEAN WELL (Guangzhou) Electronics Co., Ltd.

(Manufacturer Name)

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(Manufacturer Address)

Howay_Lin/ Engineering Manager :

(Name / Position)

(Signature)

Frank_Peng/ RD Manager :

(Name / Position)

(Signature)

GuangZhou

(Place)

Mar. 4, 2017

(Date)